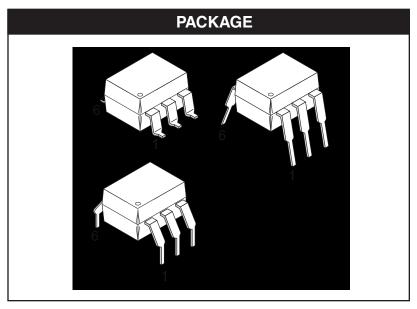
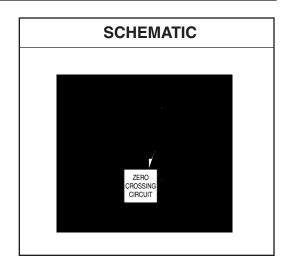


MOC3081M MOC3082M MOC3083M





DESCRIPTION

The MOC3081M, MOC3082M and MOC3083M devices consist of a GaAs infrared emitting diode optically coupled to a monolithic silicon detector performing the function of a zero voltage crossing bilateral triac driver.

They are designed for use with a discrete power triac in the interface of logic systems to equipment powered from 240 VAC lines, such as solid-state relays, industrial controls, motors, solenoids and consumer appliances, etc.

FEATURES

- Underwriters Laboratories (UL) recognized file #E90700, Volume 2
- VDE recognized file #102497 add option V (e.g., MOC3083VM)
- Simplifies logic control of 240 VAC power
- Zero voltage crossing
- dv/dt of 1500 V/µs typical, 600 V/µs guaranteed
- Compatible with Fairchild's FKPF12N80 discrete power triac

APPLICATIONS

- Solenoid/valve controls
- Lighting controls
- Static power switches
- AC motor drives
- Temperature controls
- E.M. contactors
- AC motor starters
- Solid state relays



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
Parameters	Symbol	Value	Units		
TOTAL DEVICE					
Storage Temperature	T _{STG}	-40 to +150	°C		
Operating Temperature	T _{OPR}	-40 to +85	°C		
Lead Solder Temperature	T _{SOL}	260 for 10 sec	°C		
Junction Temperature Range	T _J	-40 to +100	°C		
Isolation Surge Voltage ⁽⁴⁾ (peak AC voltage, 60Hz, 1 sec duration)	V _{ISO}	7500	Vac(pk)		
Total Device Power Dissipation @ 25°C	В	250	mW		
Derate above 25°C	bove 25°C		mW/°C		
EMITTER					
Continuous Forward Current	I _F	60	mA		
Reverse Voltage	V _R	6	V		
Total Power Dissipation 25°C Ambient	В	120	mW		
Derate above 25°C	P _D	1.41	mW/°C		
DETECTOR					
Off-State Output Terminal Voltage	V _{DRM}	800	V		
Peak Repetitive Surge Current (PW = 100 μs, 120 pps)	I _{TSM}	1	Α		
Total Power Dissipation @ 25°C Ambient		150	mW		
Derate above 25°C	P _D	1.76	mW/°C		



MOC3081M MOC3082M MOC3083M

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C Unless otherwise specified)

INDIVIDUAL COMPONENT CHARACTERISTICS						
Parameters	Test Conditions	Symbol	Min	Тур*	Max	Units
EMITTER						
Input Forward Voltage	$I_F = 30 \text{ mA}$	V _F		1.3	1.5	V
Reverse Leakage Current	V _R = 6 V	I _R		0.005	100	μA
DETECTOR						
Peak Blocking Current, Either Direction	$V_{DRM} = 800V, I_F = 0 \text{ (note 1)}$	I _{DRM1}		10	500	nA
Critical Rate of Rise of Off-State Voltage	I _F = 0 (figure 9, note 3)	dv/dt	600	1500		V/µs

TRANSFER CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)							
DC Characteristics	Test Conditions	Symbol	Device	Min	Тур*	Max	Units
	M · T · ·	I _{FT}	MOC3081M			15	
LED Trigger Current	Main Terminal Voltage = 3V (note 2)		MOC3082M			10	mA
Voltage = 6V (11816 2)			MOC3083M			5	
Peak On-State Voltage, Either Direction	$I_{TM} = 100 \text{ mA peak},$ $I_F = \text{rated } I_{FT}$	V _{TM}	All		1.8	3	V
Holding Current, Either Direction		I _H	All		500		μΑ

ZERO CROSSING CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)							
DC Characteristics	Test Conditions Symbol Device Min Typ* Max Units						
Inhibit Voltage (MT1-MT2 voltage above which device will not trigger)	I _F = Rated I _{FT}	V _{INH}	All		12	20	V
Leakage in Inhibited State	I_F = Rated I_{FT} , V_{DRM} = 800V, off state	I _{DRM2}	All		200	500	μА

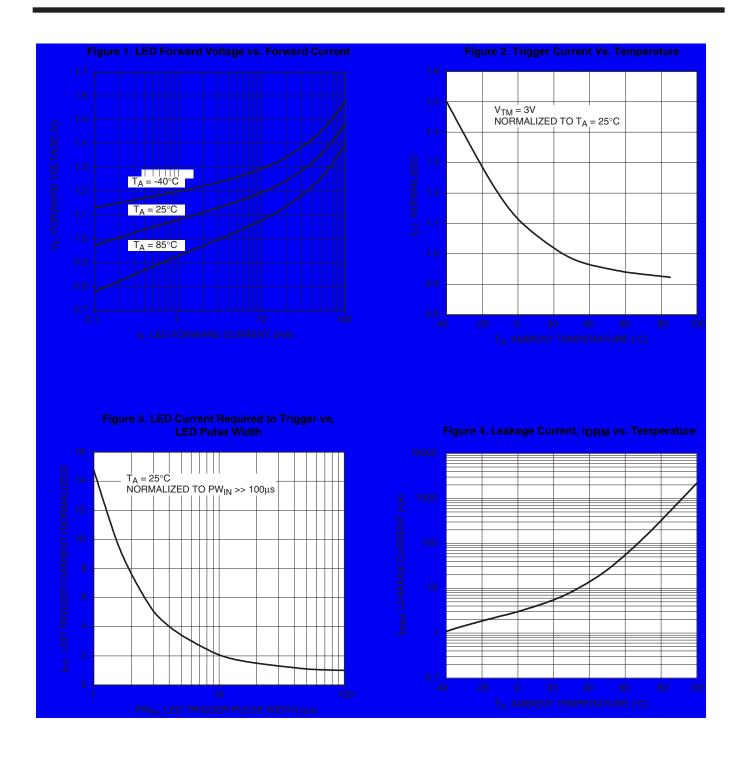
ISOLATION CHARACTERISTICS						
Characteristics	Test Conditions	Symbol	Min	Тур*	Max	Units
Input-Output Isolation Voltage	f = 60 Hz, t = 1 sec (note 4)	V _{ISO}	7500			Vac(pk)

^{*}Typical values at $T_A = 25$ °C

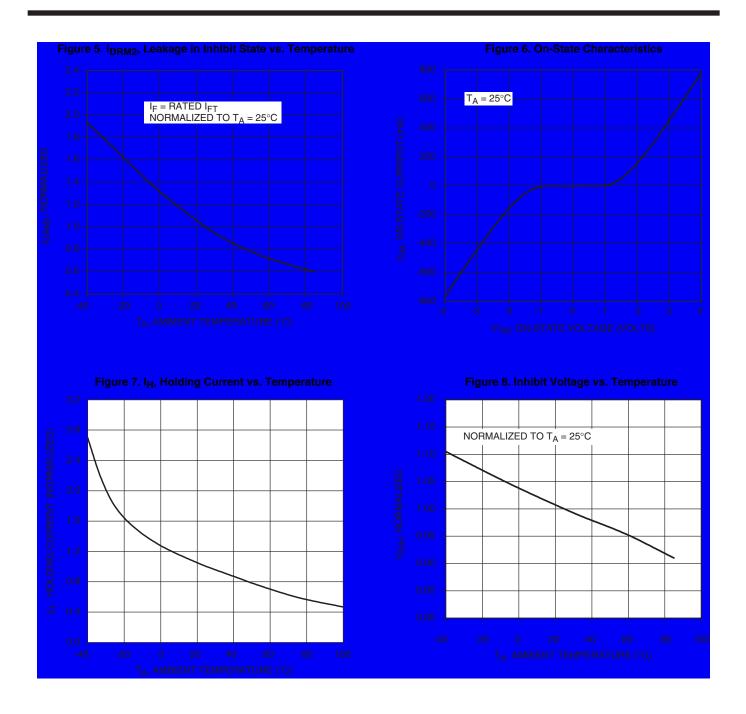
Note

- 1. Test voltage must be applied within dv/dt rating.
- 2. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT} . Therefore, recommended operating I_F lies between max I_{FT} (15 mA for MOC3081M, 10 mA for MOC3082M, 5 mA for MOC3083M) and absolute max I_F (60 mA).
- 3. This is static dv/dt. See Figure 9 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.
- 4. Isolation surge voltage, V_{ISO}, is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.



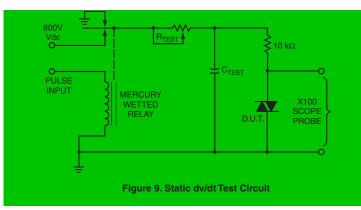




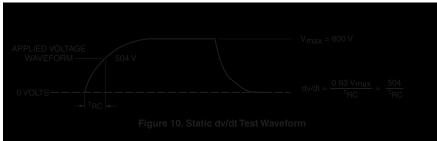




MOC3081M MOC3082M MOC3083M

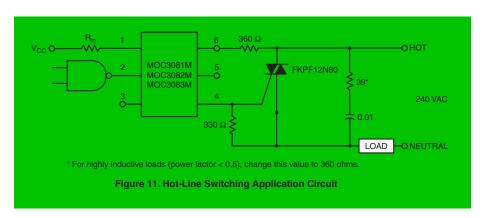


- 1. The mercury wetted relay provides a high speed repeated pulse to the D.U.T.
- 100x scope probes are used, to allow high speeds and voltages.
- 3. The worst-case condition for static dv/dt is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable R_{TEST} allows the dv/dt to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering. τ_{RC} is measured at this point and recorded.



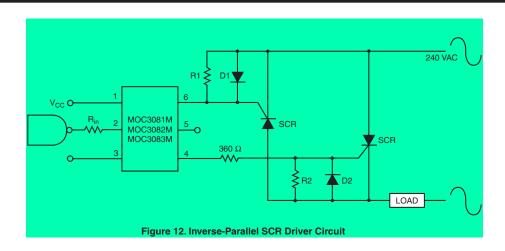
Typical circuit for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

 R_{in} is calculated so that I_F is equal to the rated I_{FT} of the part, 15 mA for the MOC3081M, 10 mA for the MOC3082M, and 5 mA for the MOC3083M. The 39 ohm resistor and 0.01 μ F capacitor are for snubbing of the triac and may or may not be necessary depending upon the particular triac and load use.





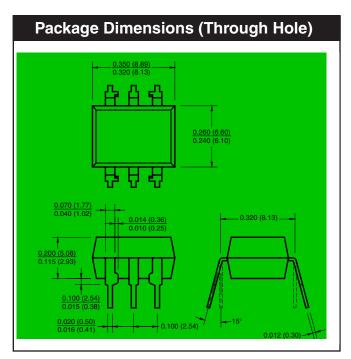
MOC3081M MOC3082M MOC3083M

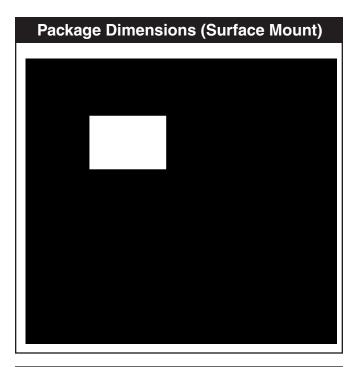


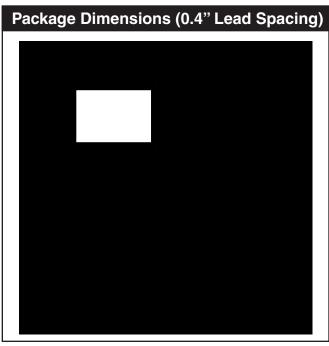
Suggested method of firing two, back-to-back SCR's with a Fairchild triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 330 ohm.

Note: This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.











NOTEAll dimensions are in inches (millimeters)

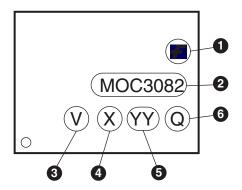


MOC3081M MOC3082M MOC3083M

ORDERING INFORMATION

Order Entry Identifier	Description		
S	Surface Mount Lead Bend		
SR2	Surface Mount; Tape and reel		
Т	0.4" Lead Spacing		
V	VDE 0884		
TV	VDE 0884, 0.4" Lead Spacing		
SV	VDE 0884, Surface Mount		
SR2V	VDE 0884, Surface Mount, Tape & Reel		

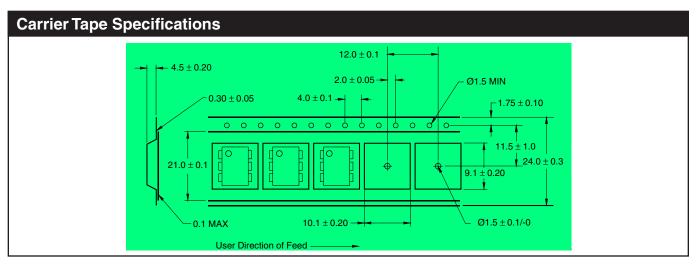
MARKING INFORMATION



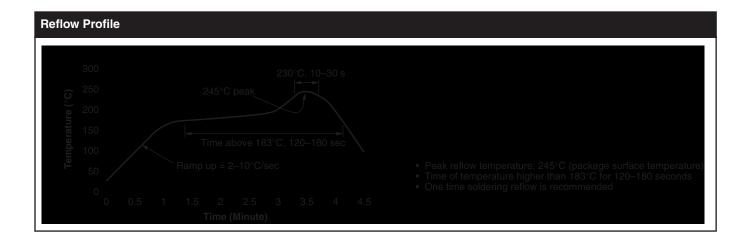
Definiti	Definitions					
1	Fairchild logo					
2	Device number					
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)					
4	One digit year code, e.g., '3'					
5	Two digit work week ranging from '01' to '53'					
6	Assembly package code					

^{*}Note – Parts that do not have the 'V' option (see definition 3 above) that are marked with date code '325' or earlier are marked in portrait format.





NOTEAll dimensions are in inches (millimeters)





MOC3081M MOC3082M MOC3083M

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